CRMKTL15120A

N-Channel 150V, 103mΩ Typ. Power MOSFET

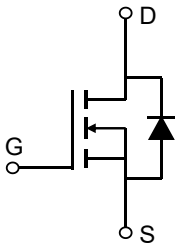
Description

Features

- 150V, 12A

  $R_{DS(ON)}$ Typ = 103mΩ @ V_{GS} = 10V

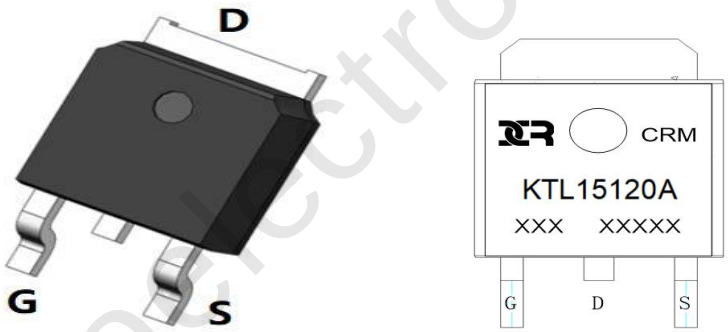
  Advanced Trench Technology
- Excellent $R_{DS(ON)}$ and Low Gate Charge
- 100% UIS TESTED!
- 100% ΔVds TESTED!



Schematic Diagram

Application

- Load Switch
- PWM Application
- Power Management



Marking and Pin Assignment

Package Marking and Ordering Information

Device	Marking	Package	Outline	Reel Size	Reel (pcs)	Per Carton (pcs)
CRMKTL15120A	CRMKTL15120A	TO-252-3L	TAPING	13"	2500	25000

Absolute Maximum Ratings (@ T_J = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V_{DS}	Drain-to-Source Voltage		150	V
V_{GS}	Gate-to-Source Voltage		±20	V
I_D	Continuous Drain Current	T_C = 25°C	12	A
		T_C = 100°C	7.2	A
I_{DM}	Pulsed Drain Current (1)		48	A
E_{AS}	Single Pulsed Avalanche Energy (2)		4.4	mJ
P_D	Power Dissipation	T_C = 25°C	50	W
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.5	°C/W
T_J, T_{STG}	Junction & Storage Temperature Range		-55 to 150	°C

Electrical Characteristics (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V	150	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 150V, V_{GS} = 0V	-	-	1.0	μA
I_{GSS}	Gate-Body Leakage Current	V_{DS} = 0V, V_{GS} = ±20V	-	-	±100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250μA	1.4	2	2.6	V
$R_{DS(ON)}$	Static Drain-Source ON-Resistance(3)	V_{GS} = 10V, I_D = 5A	-	103	134	mΩ
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{GS} = 0V, V_{DS} = 25V, f = 1MHz	-	1305	-	pF
C_{oss}	Output Capacitance		-	62	-	pF
C_{rss}	Reverse Transfer Capacitance		-	50	-	pF
Q_g	Total Gate Charge	V_{GS} = 0 to 10V V_{DS} = 75V, I_D = 5A	-	16	-	nC
Q_{gs}	Gate Source Charge		-	3.5	-	nC
Q_{gd}	Gate Drain("Miller") Charge		-	5	-	nC
Switching Characteristics						
$t_{d(on)}$	Turn-On DelayTime	V_{GS} = 10V, V_{DD} = 75V I_D= 1A, R_{GEN} = 6Ω	-	14	-	ns
t_r	Turn-On Rise Time		-	15	-	ns
$t_{d(off)}$	Turn-Off DelayTime		-	25	-	ns
t_f	Turn-Off Fall Time		-	22	-	ns
Drain-Source Diode Characteristics and Max Ratings						
I_S	Maximum Continuous Drain to Source Diode Forward Current		-	-	12	A
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	48	A
V_{SD}	Drain to Source Diode Forward Voltage	V_{GS} = 0V, I_S = 5A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time	I_F = 5A, di/dt = 100A/us	-	58	-	ns
Qrr	Body Diode Reverse Recovery Charge		-	100	-	nC

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.
2. E_{AS} condition: Starting T_J=25°C, V_{DD}=50V, V_G=10V, R_G=25ohm, L=0.5mH, I_{AS}=4.2A
3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%.

Test Circuit

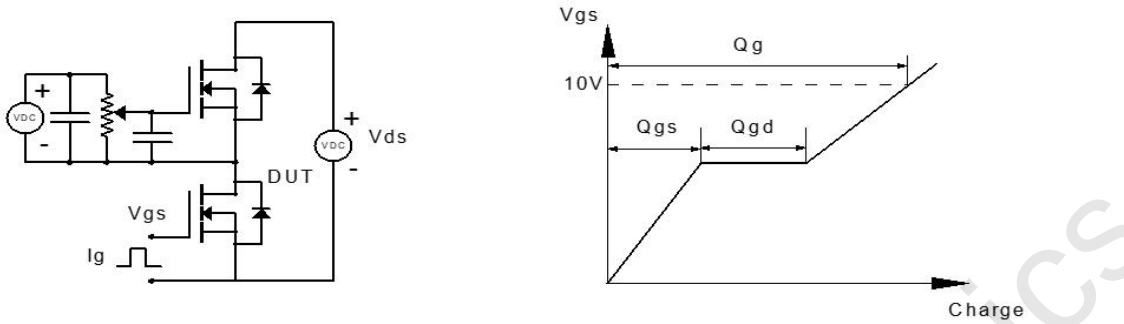


Figure 1: Gate Charge Test Circuit & Waveform

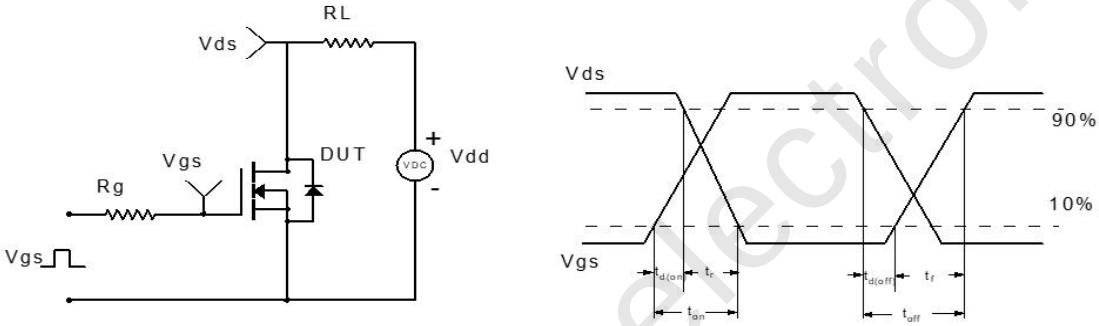


Figure 2: Resistive Switching Test Circuit & Waveform

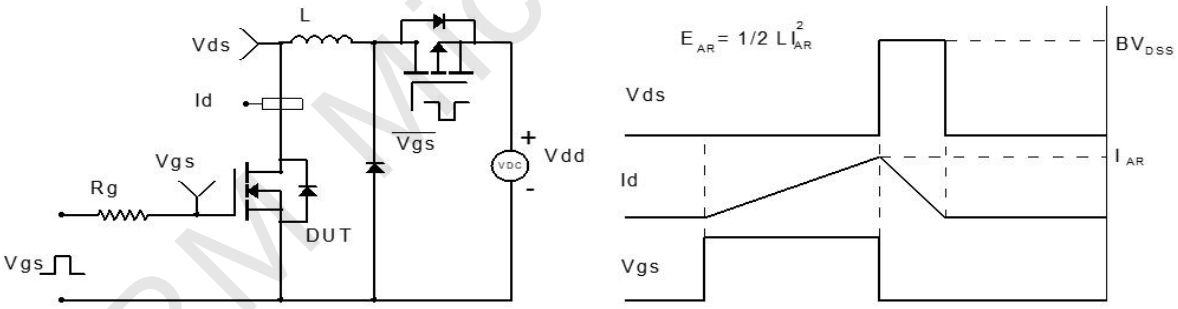


Figure 3: Unclamped Inductive Switching Test Circuit& Waveform

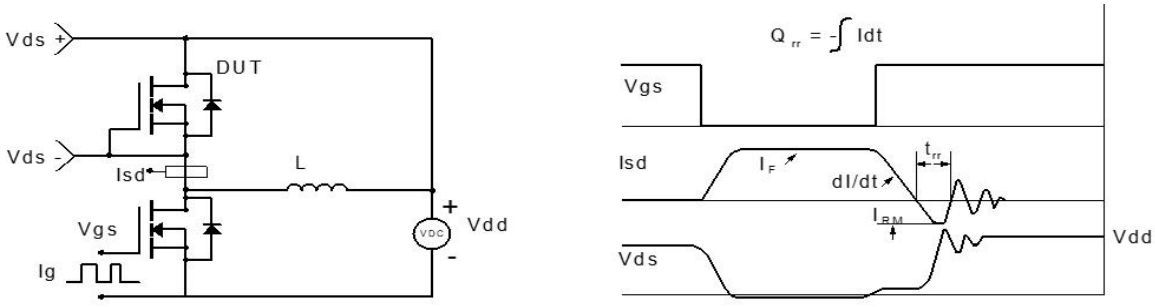
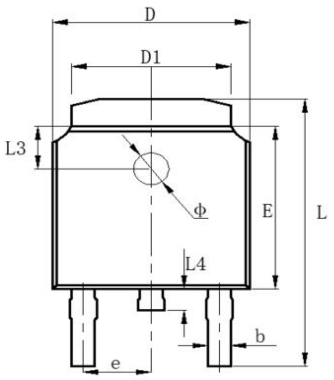
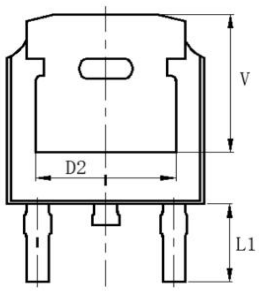
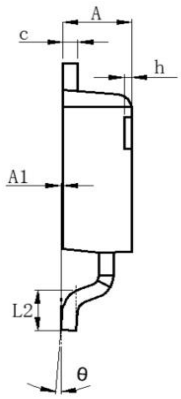


Figure 4: Diode Recovery Test Circuit & Waveform

Package Mechanical Data(TO-252-3L)







Symbol	Dimensions In Millimeters	
	Min.	Max.
A	2.200	2.400
A1	0.000	0.127
b	0.600	0.860
c	0.460	0.580
D	6.500	6.700
D1	5.100	5.460
D2	4.830 REF.	
E	6.000	6.300
e	2.186	2.386
L	9.712	10.312
L1	2.900 REF.	
L2	1.400	1.700
L3	1.600 REF.	
L4	0.600	1.000
Φ	1.100	1.300
θ	0°	8°
h	0.000	0.300
V	5.250 REF.	

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Contact information

For more information, please visit: http://www.crm-semi.tech
For sales information, please send an email to: sales@crm-semi.com